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Page 1 of 1

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Kazushi Higashi et al.FILING DATE:
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U.S. PATENT DOCUMENTS

Examiner Initial	Document No.	Date	Name	Class	Subclass	Filing Date
A						
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FOREIGN PATENT DOCUMENTS

	Document No.	Date	Country	Class	Subclass	Translation
cg	I 3-241755	10/1991	JP			Eng. abstract & Partial Trans. Attached
	J					

OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, Etc.)

cg	K	"Development of chip-on-chip bonding process at a room temperature (with copper, a bumpless bonding is also possible)", Semiconductor Sangyo Newspaper, June 12, 2002, pg. 9, Sangyo Times Inc., Tokyo, Japan.
cg	L	"Development of chip-on-chip bonding process at a room temperature by a superbonder", Electronic Materials, July 1, 2002, pp. 8-9, Vol. 41 No. 7, Kogyo Chosakai Publishing Co., Ltd., Tokyo, Japan.
cg	M	"Ultrasonic Flip Chip Bonding Technology for LSI Chip with High Pin Counts" by Kajiwara et al., from Proceedings of the 7th Symposium on Microjoining and Assembly Technology in Electronics, February 1, 2001, pp. 16166, Japan Welding Society, Tokyo, Japan.
	N	

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